The 2nd RIEC International Workshop on Spintronics

-MgO-based Magnetic Tunnel Junctions-

Date: February 15th (Thu.) – 16th (Fri.), 2007

-19:30

Venue: Laboratory for Nanoelectronics and Spintronics, RIEC Tohoku University

Program (tentative)

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Feb. 15 th (Thu.)		
9:10	Opening address H. Ohno (Organizer, Tohoku University, Japan)	
9:20	Opening remark T. Miyazaki (Tohoku University, Japan)	
9:30	Theory of spin-dependent tunneling in MgO-based junctions J. Mathon (City University London, UK)	
10:10	Theoretical study on coherent tunneling in half-metallic Heusler alloys/MgO junctions M. Shirai (Tohoku University, Japan)	
10:40	Coffee break	
11:10	Recent progress in fully epitaxial Mg-O based MTJs S. Yuasa (Advanced Industrial Science and Technology, Japan)	
11:50	Giant tunnel magnetoresistance for exchange biased and pseudo-spin valve CoFeB/MgO/CoFeB magnetic tunnel junctions Y. M. Lee (Tohoku University, Japan)	
12:20	Lunch	
14:00	Characterazations on the polycrystalline CoFeB/MgO/CoFeB-based magnetic tunnel junctions Y. S. Choi (Canon Anelva, Co., Japan)	
14:40	XPS, STS and STEM studies on MgO tunnel barrier layers in MTJ (tentative) J. Read (Cornell University, USA)	
15:10	Crystallographic structure and giant TMR of CoFeB/MgO/CoFeB-MTJs M. Tsunoda (Tohoku University, Japan)	
15:40	Coffee break	
16:10	MgO double tunnel junctions M. Coey (University of Dublin, Ireland)	
16:50 (-17:20)	How to play with the fastidious MgO applicable to STT-MRAM K. H. Shin (Korea Institute of Science and Technology, Korea)	
18:00	Banquet —Sendai Kokusai Hotel; "Steakery Thirty"—	

(SS30 Bldg. 2-6-1 Chuo, Aoba-ku, Sendai phone: 022-267-8830)

Feb. 16th (Fri.)

9:30	Spin-torque-switchable nano-structured MgO magnetic tunnel junctions
	J. Sun (Thomas J. Watson Research Center, IBM, USA)
10:10	Spin Transfer Switching in MTJ with Nano-Second Pulse Widths
	Y. Huai (Grandis Inc., USA)
10:50	Coffee break
11:10	Current-induced magnetization switching and thermal stability in nano-scale MgO based magnetic tunnel junctions
	J. Hayakawa (Hitachi Ltd., Japan)
11:40	Large power microwave excitations induced by spin-transfer in MgO-based magnetic tunnel junctions
	A. Deac (Osaka University, Japan)
12:10	Lunch
14:00	Spin polarized tunneling in MgO based magnetic tunnel junctions
	S. Parkin (Almaden Research Center, IBM, USA)
14:40	Giant TMR at room temperature using Co-based Heusler alloy electrodes and a MgO barrier
	K. Inomata (National Institute for Materials Science, Japan)
15:10	Spin-dependent tunneling in fully epitaxial magnetic tunnel junctions with a Heusler alloy thin film and a MgO tunnel barrier
	M. Yamamoto (Hokkaido University, Japan)
15:40	Coffee break
16:10	Tunnel magnetoresistance in MTJs with Co ₂ MnSi electrode and MgO barrier
	M. Oogane (Tohoku University, Japan)
16:40	Thermal stability of exchange-couple trilayers for high density magnetic random access memory
	S. H. Lim (Korea University, Korea)
17:10	Closing address
-17:20	H. Ohno (Tohoku University, Japan)